NSN 5962-01-539-6386

Memory Microcircuit - Page 1 of 1



| view Online at https://aerobasegroup.com/hsn/5962-01-559-6566 |
|--|
| Operating Tempurature Range: |
| -55.0/+125.0 degrees celsius |
| Inclosure Configuration: |
| Dual-in-line |
| Case Outline Source And Designator: |
| X mil-m-38510 |
| Product Name: |
| Microcircuit, memory, digital cmos, 64k x 8 eeprom, monolithic silicon |
| Voltage Rating And Type Per Characteristic: |
| 4.5 volts power source and 5.5 volts power source |
| Memory Device Type: |
| Eeprom |
| Memory Capacity: |
| 64k x 8 |
| Terminal Type And Quantity: |
| 32 printed circuit |
| Shelf Life: |
| N/a |
| Unit Of Measure: |
| |
| Demilitarization: |
| Yes - demil/mli |
| Fiig: |
| A458a0 |